# MCR218-2, MCR218-4, MCR218-6

Preferred Device

### **Silicon Controlled Rectifiers**

#### **Reverse Blocking Thyristors**

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supplies; or wherever half-wave silicon gate-controlled, solid-state devices are needed.

#### Features

- Glass-Passivated Junctions
- Blocking Voltage to 400 Volts
- TO-220 Construction Low Thermal Resistance, High Heat Dissipation and Durability
- Pb–Free Packages are Available\*

#### **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (T <sub>J</sub> = -40 to 125°C, Gate Open) MCR218-2 MCR218-4 MCR218-6	V <sub>drm,</sub> V <sub>rrm</sub>	50 200 400	V
On-State RMS Current (180° Conduction Angles; T <sub>C</sub> = 70°C)	I <sub>T(RMS)</sub>	8.0	A
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, $T_J$ = 125°C)	I <sub>TSM</sub>	100	A
Circuit Fusing Considerations (t = 8.3 ms)	l <sup>2</sup> t	26	A <sup>2</sup> s
Forward Peak Gate Power (Pulse Width $\leq$ 1.0 $\mu s,T_C$ = 70°C)	P <sub>GM</sub>	5.0	W
Forward Average Gate Power (t = 8.3 ms, $T_C = 70^{\circ}C$ )	P <sub>G(AV)</sub>	0.5	W
Forward Peak Gate Current (Pulse Width $\leq$ 1.0 $\mu s,~T_C$ = 70°C)	I <sub>GM</sub>	2.0	A
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

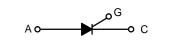
 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

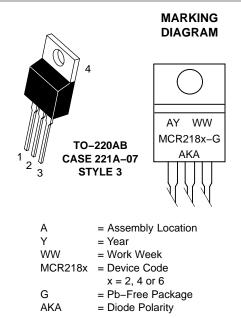


#### **ON Semiconductor®**

http://onsemi.com

SCRs 8 AMPERES RMS 50 thru 400 VOLTS





#### **ORDERING INFORMATION**

Device	Package	Shipping
MCR218-2	TO220AB	500 Units/Bulk
MCR218-2G	TO220AB (Pb–Free)	500 Units/Bulk
MCR218-4	TO220AB	500 Units/Bulk
MCR218-4G	TO220AB (Pb–Free)	500 Units/Bulk
MCR218-6	TO220AB	500 Units/Bulk
MCR218-6G	TO220AB (Pb–Free)	500 Units/Bulk

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**Preferred** devices are recommended choices for future use and best overall value.

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#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{ extsf{ heta}JC}$	2.0	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	ΤL	260	°C

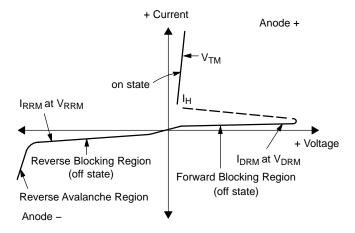
#### **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	·		•	•	•
Peak Repetitive Forward or Reverse Blocking Current	I <sub>DRM</sub> , I <sub>RRM</sub>				
$(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, Gate Open)$ $T_J = 25^{\circ}C$		-	-	10	μΑ
$T_{J} = 125^{\circ}C$		-	-	2.0	mA
ON CHARACTERISTICS	·	•	•	•	•
Peak Forward On-State Voltage (Note 2) (I <sub>TM</sub> = 16 A Peak)	V <sub>TM</sub>	-	1.5	1.8	V
Gate Trigger Current (Continuous dc) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ohms)	I <sub>GT</sub>	-	10	25	mA
Gate Trigger Voltage (Continuous dc) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ohms)	V <sub>GT</sub>	-	-	1.5	V
Gate Non–Trigger Voltage (Rated 12 V, R <sub>L</sub> = 100 Ohms, T <sub>J</sub> = 125°C)	V <sub>GD</sub>	0.2	-	-	V
Holding Current (V <sub>D</sub> = 12 Vdc, Initiating Current = 200 mA, Gate Open)	Ι <sub>Η</sub>	-	16	30	mA
DYNAMIC CHARACTERISTICS		•	•	•	•
Critical Rate-of-Rise of Off-State Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , Exponential Waveform, Gate Open, T <sub>J</sub> = 125°C)	dv/dt	-	100	_	V/µs

2. Pulse Test: Pulse Width = 1.0 ms, Duty Cycle  $\leq$  2%.

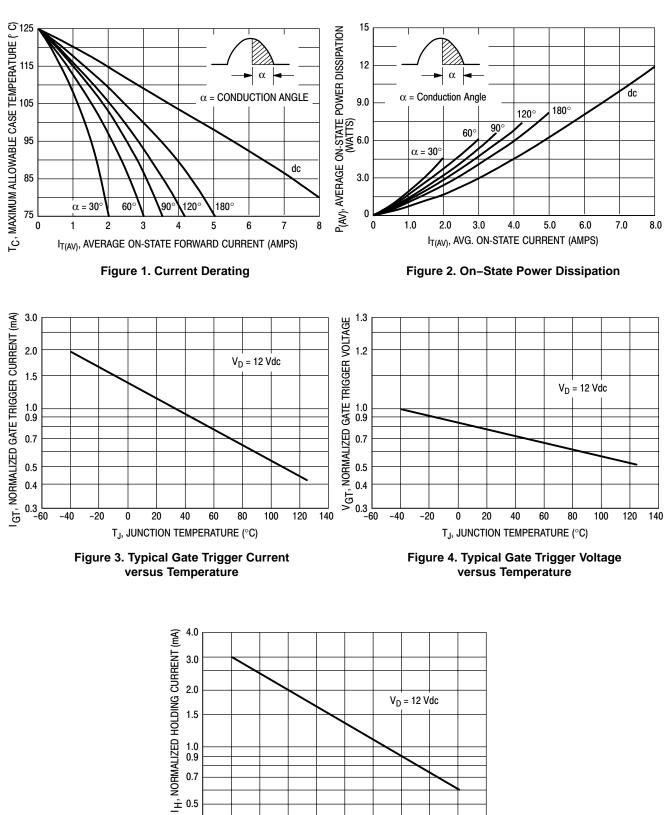
#### Voltage Current Characteristic of SCR

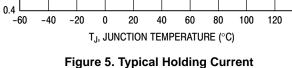
Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Off State Forward Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Off State Reverse Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Peak On State Voltage
I <sub>H</sub>	Holding Current



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#### MCR218-2, MCR218-4, MCR218-6





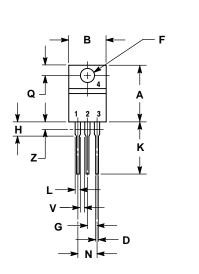
versus Temperature

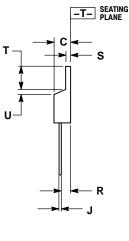
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#### PACKAGE DIMENSIONS

**TO-220AB** CASE 221A-07 **ISSUE AA** 





NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIN	IETERS
DIM	MIN	MIN MAX		MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

PIN 1. CATHODE ANODE 2. 3. GATE 4 ANODE

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